







Continental Device India Limited

An IS/ISO 9002 and IECQ Certified Manufacturer

PNP/NPN COMPLEMENTARY PLANAR SILICON TRANSISTORS



CSA1013 (PNP) CSC2383 (NPN) TO-237 BCE

Vertical Deflection Output & Class B Sound Output Applications of Colour T.V

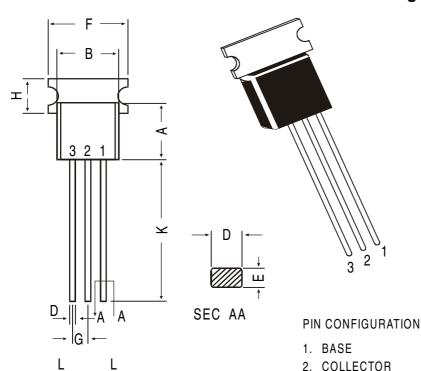
ABSOLUTE MAXIMUM RATINGS(Ta=25deg C unless otherwise specified)

DESCRIPTION	SYMBOL		VALUE	57		
Collector -Base Voltage	VCBO		160	-4 5	一车切四	
Collector -Emitter Voltage	VCEO		160			V
Emitter Base Voltage	VEBO		6.0			V
Collector Current	IC		1.0			Α
Base Current	IB		500	m		
Collector Power Dissipation	PC		900			mW
Operating And Storage Junction	Tj, Tstg		-55 to +150			deg C
Temperature Range	WW.DZSO					
ELECTRICAL CHARACTERISTICS (7	Γa=25 deg C L	Inless Otherwise Spe	ecified)			
DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Collector -Emitter Voltage	VCEO	IC=10mA, IB=0	160	-	- 17-10	V
Collector Cut off Current	ICBO	VCB=150V, IE=0	- 1	454	1.0	uA
Emitter Cut off Current	IEBO	VEB=6V, IC=0		42.7	1.0	uA

Collector -Emitter Voltage VCEO IC=10mA, IB=0 160 - - Collector Cut off Current ICBO VCB=150V, IE=0 - - 1.0 Emitter Cut off Current IEBO VEB=6V, IC=0 - - 1.0 DC Current Gain hFE* IC=200mA, VCE=5V 60 - 320 Collector Emitter Saturation Voltage VCE(Sat)* IC=500mA, IB=50mA - - 1.5 Base Emitter on Voltage VBE(on)* IC=5mA, VCE=5V 0.45 - 0.75 Dynamic Characteristics Output Capacitance Cob NPN VCB=10V, IE=0, results of the company of the com	PTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Emitter Cut off Current IEBO VEB=6V, IC=0 - - 1.0 DC Current Gain hFE* IC=200mA,VCE=5V 60 - 320 Collector Emitter Saturation Voltage VCE(Sat)* IC=500mA,IB=50mA - - 1.5 Base Emitter on Voltage VBE(on)* IC=5mA, VCE=5V 0.45 - 0.75 Dynamic Characteristics Output Capacitance Cob NPN VCB=10V, IE=0,	-Emitter Voltage	VCEO	IC=10mA, IB=0	160	-	-17.0	V
DC Current Gain hFE* IC=200mA,VCE=5V 60 - 320 Collector Emitter Saturation Voltage VCE(Sat) * IC=500mA,IB=50mA - - 1.5 Base Emitter on Voltage VBE(on)* IC=5mA, VCE=5V 0.45 - 0.75 Dynamic Characteristics Output Capacitance Cob NPN VCB=10V, IE=0,	Cut off Current	ICBO	VCB=150V, IE=0	-	4	1.0	uA
Collector Emitter Saturation Voltage VCE(Sat) * IC=500mA,IB=50mA - - 1.5 Base Emitter on Voltage VBE(on)* IC=5mA, VCE=5V 0.45 - 0.75 Dynamic Characteristics Output Capacitance Cob NPN VCB=10V, IE=0, results for the company of the com	ut off Current	IEBO	VEB=6V, IC=0	-	HE- 7	1.0	uA
Dynamic Characteristics Cob NPN VCB=10V, IE=0, f=1MHz - - 20 f=1MHz Gain Bandwidth Product ft NPN VCE=5V,IC=200mA, 20 100 - - - 35 description	nt Gain	hFE*	IC=200mA,VCE=5V	60	MAIN	320	
Dynamic Characteristics Cob NPN VCB=10V, IE=0, f=1MHz - - - 20 PNP - - 35 Gain Bandwidth Product ft NPN VCE=5V,IC=200mA, 20 100 -	Emitter Saturation Voltage	VCE(Sat) *	IC=500mA,IB=50mA	EL I	-	1.5	V
Output Capacitance Cob NPN VCB=10V, IE=0, f=1MHz - - - 20 FNP PNP 35 Gain Bandwidth Product ft NPN VCE=5V,IC=200mA, 20 100 -	itter on Voltage	VBE(on)*	IC=5mA, VCE=5V	0.45	-	0.75	V
Output Capacitance Cob NPN VCB=10V, IE=0, f=1MHz - - - 20 Find Hz PNP 35 Gain Bandwidth Product ft NPN VCE=5V,IC=200mA, 20 100 -							
f=1MHz PNP 35 Gain Bandwidth Product ft NPN VCE=5V,IC=200mA, 20 100 -	Characteristics						
PNP 35 Gain Bandwidth Product ft NPN VCE=5V,IC=200mA, 20 100 -	apacitance	Cob NPN	VCB=10V, IE=0,	-	-	20	pF
Gain Bandwidth Product ft NPN VCE=5V,IC=200mA, 20 100 -	390 7-1-2		f=1MHz				_
		PNP		-	-	35	pF
PNP 15 50 -	dwidth Product	ft NPN	VCE=5V,IC=200mA,	20	100	石切り	MHz
		PNP		15	50	GE-G'	MHz
CLASSIFICATION R O Y	ICATION	R	0	Υ	WWW.	.0	
hFE * 60-120 100-200 160-320		60-120	100-200	160-320			
*Pulse Test : Pulse Width =300us, Duty Cycle=2%	est : Pulse Width =300us, Duty	Cycle=2%	FN 97/((2) =				



TO-237 Plastic Package



	DIM	MIN.	MAX.	
	Α	4.32	5.33	
B C D	4.45	5.20		
	3.18	4.19		
	0.41	0.55		
	Ш	0.35	0.50	
E.	F	_	5.40	
.⊑ G	1.14	1.40		
Suc	Ι	_	2.54	
All diminsions in mm.	K	12.70		
ië [L	5 DEG		
₩ W	7	1.14	1.53	

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-237 Bulk	1K/polybag	240 gm/1K pcs	3" x 7.5" x 7.5"	5.0K	17" x 15" x 13.5"	80.0K	26.2 kgs
TO-237 T&A	2K/ammo box	725 gm/2K pcs	12.5" x 8" x 1.8"	2.0K	17" x 15" x 13.5"	32.0K	13.8 kgs

3. EMITTER

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished on the CDIL Web Site/CD is believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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